NSN 5962-01-333-2958



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-01-333-2958 **Overall Height:** Between 0.260 inches and 0.370 inches **Body Length:** Between 1.230 inches and 1.285 inches **Body Width:** Between 0.245 inches and 0.285 inches **Body Height:** Between 0.080 inches and 0.205 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Electrostatic sensitive and hermetically sealed and burn in and bipolar and programmable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 14 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 30.00 nanoseconds propagation delay time, low to high level output and 30.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 24 printed circuit Shelf Life: N/a

Demilitarization: Yes - demil/mli

Unit Of Measure:

NSN 5962-01-333-2958

Memory Microcircuit - Page 2 of 2



Fiig:

A458a0